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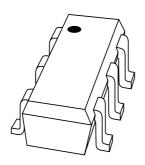
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



BC846S NPN general purpose double transistor

Product data sheet Supersedes data of 1999 May 28 1999 Sep 01



NPN general purpose double transistor

BC846S

FEATURES

- Two transistors in one package
- · Reduces number of components and board space
- No mutual interference between the transistors.

APPLICATIONS

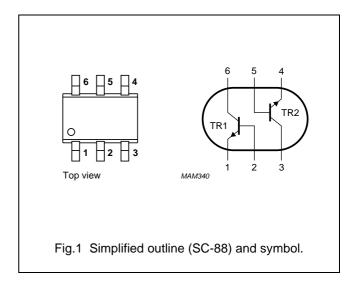
General purpose switching and small signal amplification.

DESCRIPTION

NPN double transistor in an SC-88 (SOT363) plastic six lead package.

PINNING

PIN		DESCRIPTION
1, 4	emitter	TR1; TR2
2, 5	base	TR1; TR2
6, 3	collector	TR1; TR2



MARKING

TYPE NUMBER	MARKING CODE
BC846S	4Ft

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transis	tor		<u> </u>	-	
V _{CBO}	collector-base voltage	open emitter	_	80	V
V _{CEO}	collector-emitter voltage	open base	_	65	V
V _{EBO}	emitter-base voltage	open collector	_	6	V
I _C	collector current (DC)		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C
Per device	•	•	<u>.</u>		•
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW

Note

1. Refer to SC-88 (SOT363) standard mounting conditions.

NPN general purpose double transistor

BC846S

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	416	K/W

Note

1. Refer to SC-88 (SOT363) standard mounting conditions.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Per transistor							
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 30 V	_	_	15	nA	
		I _E = 0; V _{CB} = 30 V; T _j = 150 °C	-	-	5	μΑ	
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	-	-	100	nA	
h _{FE}	DC current gain	I _C = 2 mA; V _{CE} = 5 V	110	-	_		
V _{CEsat}	collector-emitter saturation	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	_	100	mV	
	voltage	I _C = 100 mA; I _B = 5 mA; note 1	_	_	300	mV	
V _{BEsat}	base-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	_	770	_	mV	
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$	Ī-	Ī-	1.5	pF	
f _T	transition frequency	I _C = 10 mA; V _{CE} = 5 V; f = 100 MHz	100	_	_	MHz	

Note

1. Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

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BC846S

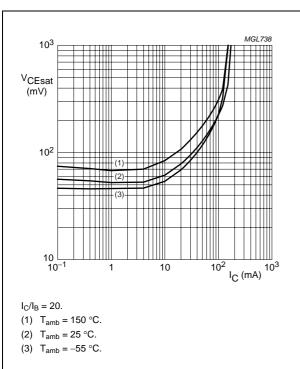
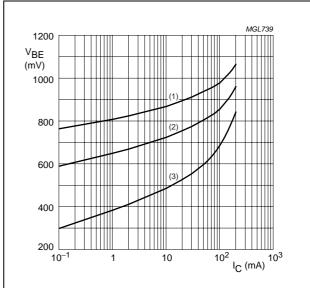


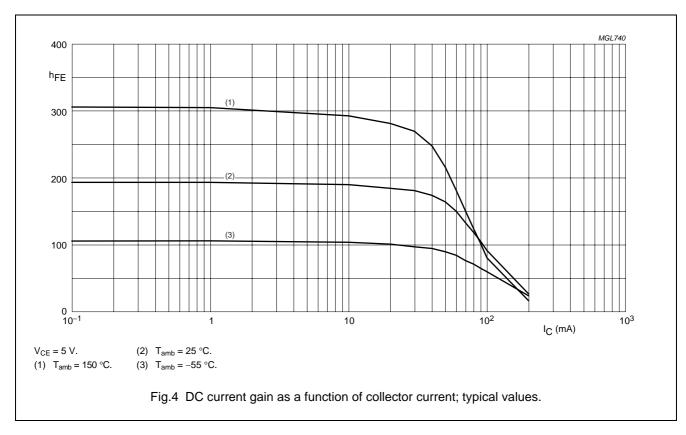
Fig.2 Collector-emitter saturation voltage as a function of collector current; typical values.



 $V_{CE} = 5 \text{ V}.$

- (1) $T_{amb} = -55 \, ^{\circ}C$.
- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = 150 \, ^{\circ}C$.

Fig.3 Base-emitter voltage as a function of collector current; typical values.



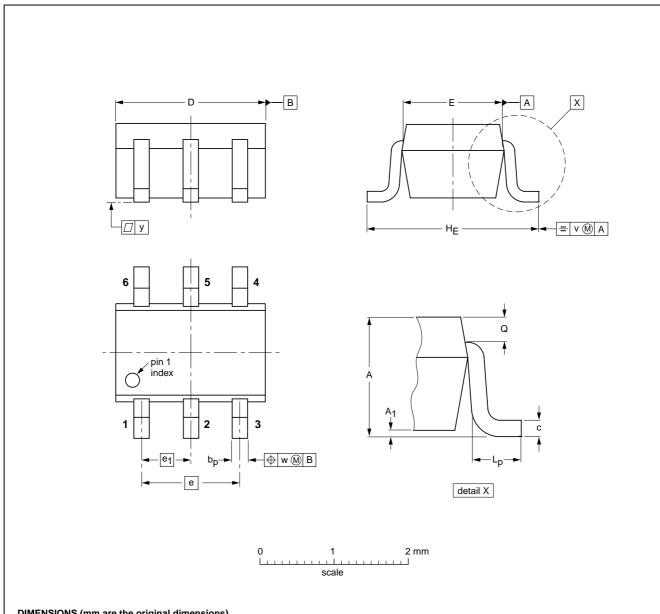
NPN general purpose double transistor

BC846S

PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT363



DIMENSIONS (mm are the original dimensions)

			-											
UNIT	Α	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	Q	v	w	у
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT363			SC-88			97-02-28

NPN general purpose double transistor

BC846S

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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NXP Semiconductors

Customer notification

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For additional information please visit: http://www.nxp.com

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